

2-Gbit, 2112-byte/1056-word page multiplane architecture, 1.8 V or 3 V, NAND flash memories

Manufacturers	STMicroelectronics, Inc
Package/Case	TSOP-48
Product Type	Memory
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for NAND02GW3B2DN6E or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

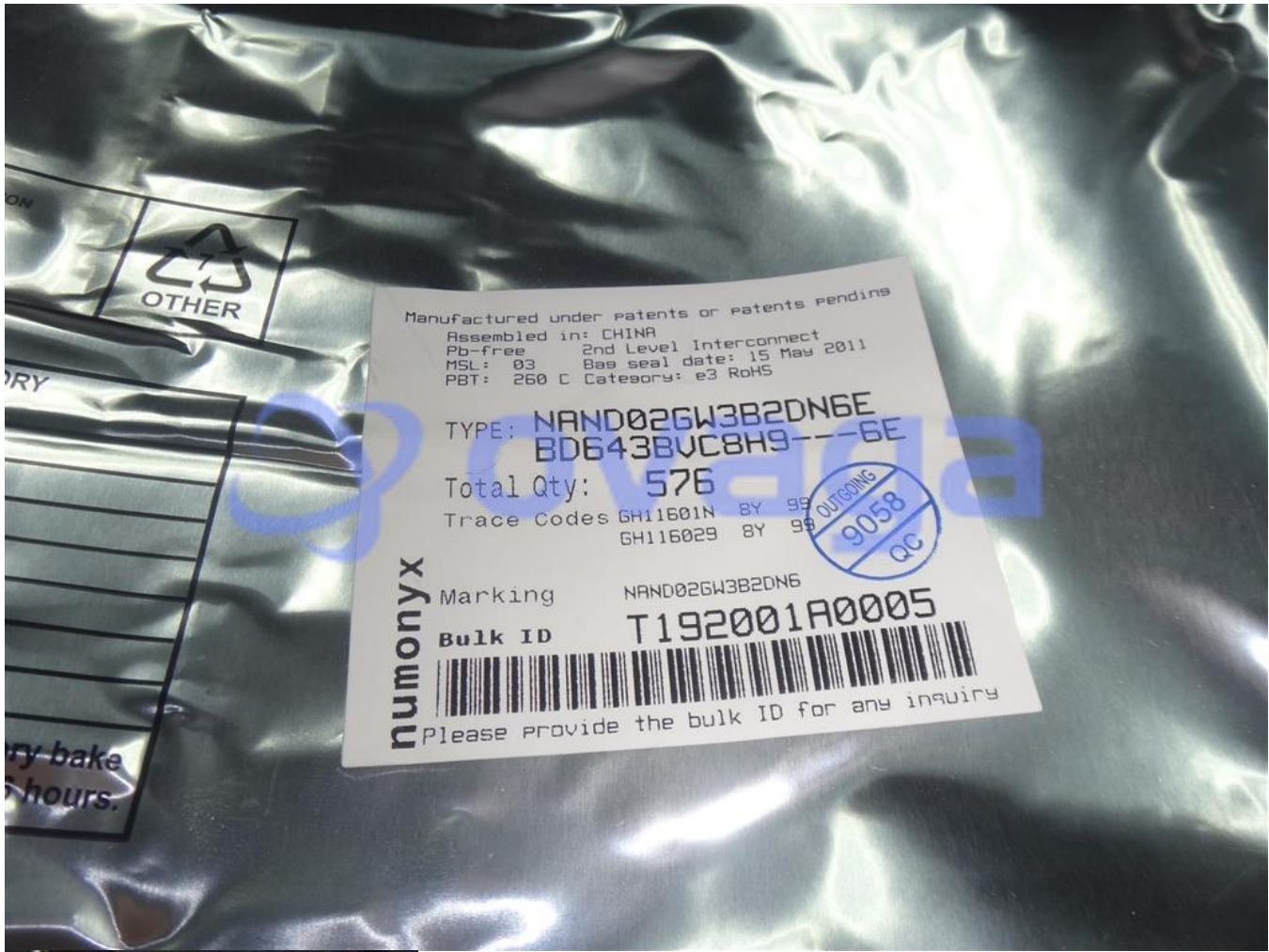
NAND02GW3B2DN6E is a part number for a NAND Flash memory chip produced by Micron Technology. Here are some details about this chip:

Features

- 2Gb (Gigabit) density
- 3.3V operating voltage
- SLC (Single-Level Cell) technology
- NAND interface
- Industrial temperature range (-40°C to +85°C)
- 48-ball VFBGA (Very Fine Pitch Ball Grid Array) package

Application

- Embedded systems
- Automotive applications
- Industrial control systems
- Medical equipment
- Aerospace and defense systems
- Consumer electronics



Related Products



[NAND01GW3B2BN6F](#)

STMicroelectronics, Inc
TSOP-48



[NAND512W3A2BN6E](#)

STMicroelectronics, Inc
TSOP-1-48



[NAND512W3A2CN6E](#)

STMicroelectronics, Inc
TSOP-48



[NAND08GW3B2CN6](#)

STMicroelectronics, Inc
TSOP48



[NAND08GW3B2CN6](#)

STMicroelectronics, Inc
TSOP48



[M29W640GB-70NA6](#)

STMicroelectronics, Inc
TSOP-48



[NAND512W3A2BZA6](#)

STMicroelectronics, Inc
TFBGA63



[NAND01GW3B2CN6E](#)

STMicroelectronics, Inc
TSOP48